DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

HEF4585B
MSI
4-bit magnitude comparator

Product specification
File under Integrated Circuits, IC04

January 1995

DESCRIPTION

The HEF4585B is a 4-bit magnitude comparator which compares two 4-bit words (A and B), whether they are 'less than', 'equal to', or 'greater than'. Each word has four parallel inputs (A_0 to A_3 and B_0 to B_3); A_3 and B_3 being the most significant inputs. Three outputs are provided; A greater than B ($O_{A>B}$), A less than B ($O_{A<B}$) and A equal to B ($O_{A=B}$). Three expander inputs ($I_{A>B}$, $I_{A<B}$ and $I_{A=B}$) allow cascading of the devices without external gates.

For proper compare operation the expander inputs to the least significant position must be connected as follows: $I_{A=B}$ = $I_{A>B}$ = HIGH, $I_{A<B}$ = LOW. For words greater than 4-bits, units can be cascaded by connecting outputs $O_{A<B}$ and $O_{A=B}$ to the corresponding inputs of the next significant comparator (input $I_{A>B}$ is connected to a HIGH).

Operation is not restricted to binary codes, the devices will work with any monotonic code. The function table describes the operation of the device under all possible logic conditions.

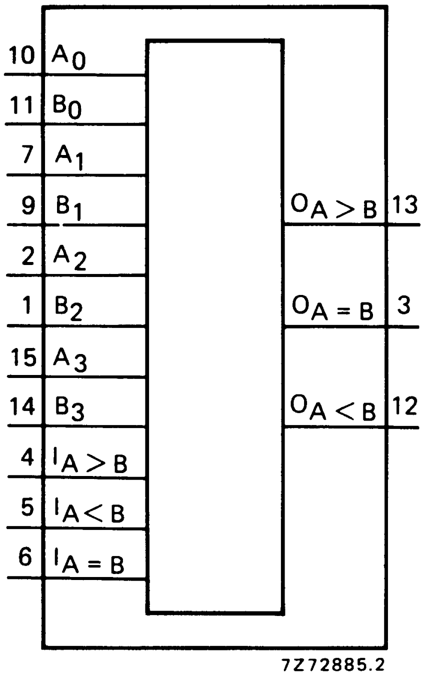

Fig.1 Functional diagram.

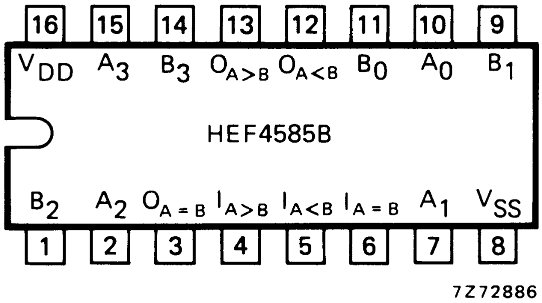

Fig.2 Pinning diagram.

HEF4585BP(N):	16-lead DIL; plastic (SOT38-1)
HEF4585BD(F):	16-lead DIL; ceramic (cerdip) (SOT74)
HEF4585BT(D):	16-lead SO; plastic (SOT109-1)

( ): Package Designator North America

PINNING

A_0 to A_3	word A parallel inputs
B_0 to B_3	word B parallel inputs
$I_{A>B}$, $I_{A<B}$, $I_{A=B}$	expander inputs
$O_{A>B}$	A greater than B output
$O_{A<B}$	A less than B output
$O_{A=B}$	A equal to B output

FAMILY DATA, I_{DD} LIMITS category MSI

See Family Specifications

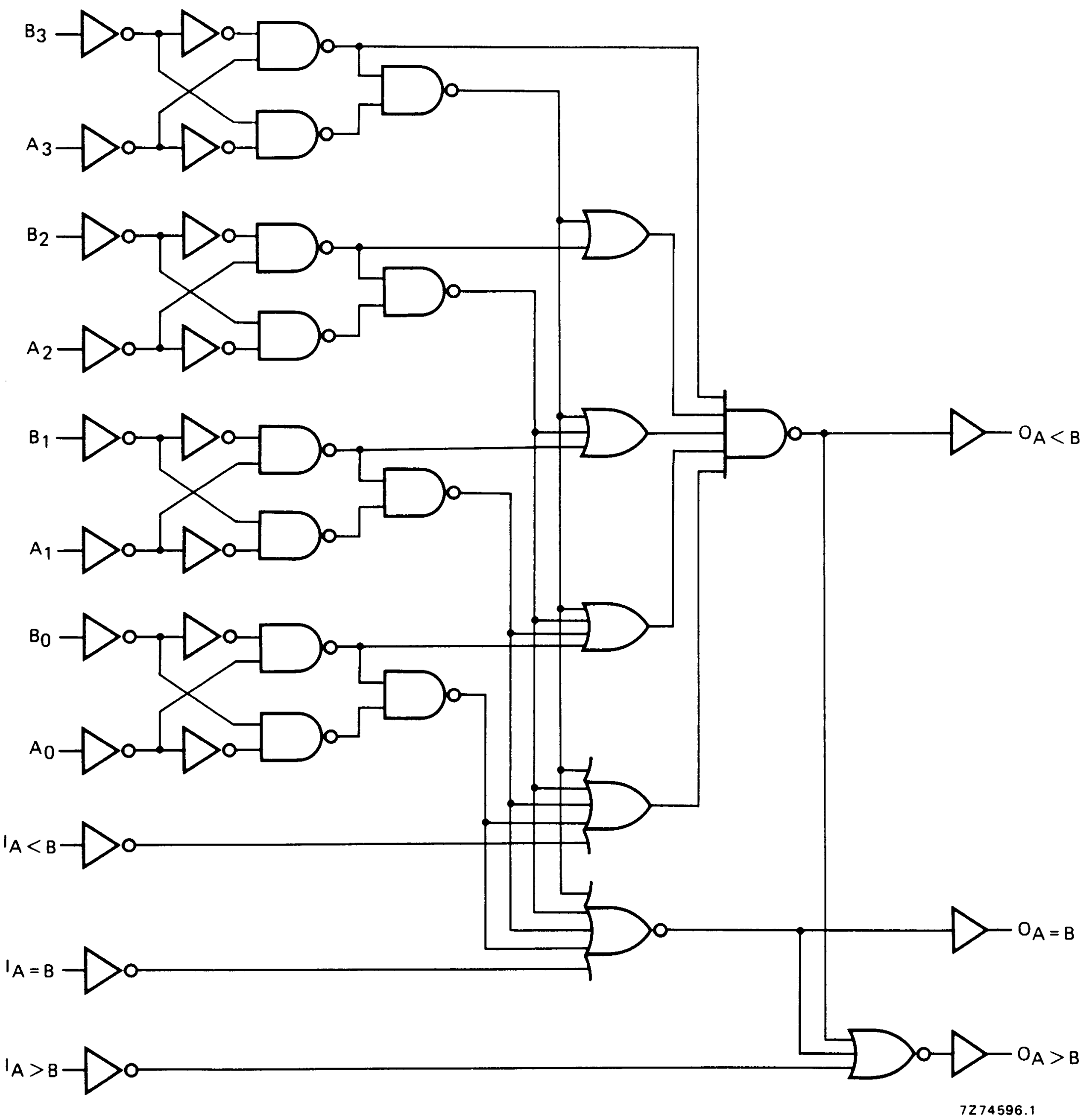

Fig.3 Logic diagram.

FUNCTION TABLE

COMPARING INPUTS				CASCADING INPUTS			OUTPUTS		
A_3, B_3	A_2, B_2	A_1, B_1	A_0, B_0	$I_{A>B}$	$I_{A<B}$	$I_{A=B}$	$O_{A>B}$	$O_{A<B}$	$O_{A=B}$
$A_3 > B_3$	X	X	X	H	X	X	H	L	L
$A_3 < B_3$	X	X	X	X	X	X	L	H	L
$A_3 = B_3$	$A_2 > B_2$	X	X	H	X	X	H	L	L
$A_3 = B_3$	$A_2 < B_2$	X	X	X	X	X	L	H	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 > B_1$	X	H	X	X	H	L	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 < B_1$	X	X	X	X	L	H	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 > B_0$	H	X	X	H	L	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 < B_0$	X	X	X	L	H	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	X	L	H	L	L	H
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	H	L	L	H	L	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	X	H	L	L	H	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	X	H	H	L	H	H
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	L	L	L	L	L	L

Notes

1. H = HIGH state (the more positive voltage)
   L = LOW state (the less positive voltage)
   X = state is immaterial

The upper 11 lines describe the normal operation under all conditions that will occur in a single device or in a serial expansion scheme.

The lower 2 lines describe the operation under abnormal conditions on the cascading inputs. These conditions occur when the parallel expansion technique is used.

AC CHARACTERISTICS

V_{SS} = 0 V; T_{amb} = 25 °C; C_L = 50 pF; input transition times ≤ 20 ns

	V_{DD} V	SYMBOL	MIN.	TYP.	MAX.		TYPICAL EXTRAPOLATION FORMULA
Propagation delays							
A_n, B_n → O_n	5			160	320	ns	133 ns + (0,55 ns/pF) C_L
HIGH to LOW	10	t_{PHL}		65	130	ns	54 ns + (0,23 ns/pF) C_L
	15			45	90	ns	37 ns + (0,16 ns/pF) C_L
	5			150	300	ns	123 ns + (0,55 ns/pF) C_L
LOW to HIGH	10	t_{PLH}		60	120	ns	49 ns + (0,23 ns/pF) C_L
	15			45	90	ns	37 ns + (0,16 ns/pF) C_L
I_n → O_n	5			110	220	ns	83 ns + (0,55 ns/pF) C_L
HIGH to LOW	10	t_{PHL}		45	90	ns	34 ns + (0,23 ns/pF) C_L
	15			30	60	ns	22 ns + (0,16 ns/pF) C_L
	5			120	240	ns	93 ns + (0,55 ns/pF) C_L
LOW to HIGH	10	t_{PLH}		50	100	ns	39 ns + (0,23 ns/pF) C_L
	15			35	70	ns	27 ns + (0,16 ns/pF) C_L
Output transition times	5			60	120	ns	10 ns + (1,0 ns/pF) C_L
HIGH to LOW	10	t_{THL}		30	60	ns	9 ns + (0,42 ns/pF) C_L
	15			20	40	ns	6 ns + (0,28 ns/pF) C_L
	5			60	120	ns	10 ns + (1,0 ns/pF) C_L
LOW to HIGH	10	t_{TLH}		30	60	ns	9 ns + (0,42 ns/pF) C_L
	15			20	40	ns	6 ns + (0,28 ns/pF) C_L

	V_{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power	5	$1250\ f_i + \sum (f_oC_L) \times V_{DD}^2$	where
dissipation per	10	$5500\ f_i + \sum (f_oC_L) \times V_{DD}^2$	f_i = input freq. (MHz)
package (P)	15	$15\,000\ f_i + \sum (f_oC_L) \times V_{DD}^2$	f_o = output freq. (MHz)
			C_L = load capacitance (pF)
			$\sum (f_oC_L)$ = sum of outputs
			V_{DD} = supply voltage (V)

APPLICATION INFORMATION

Some examples of applications for the HEF4585B are:

- Process controllers.
- Servo-motor control.

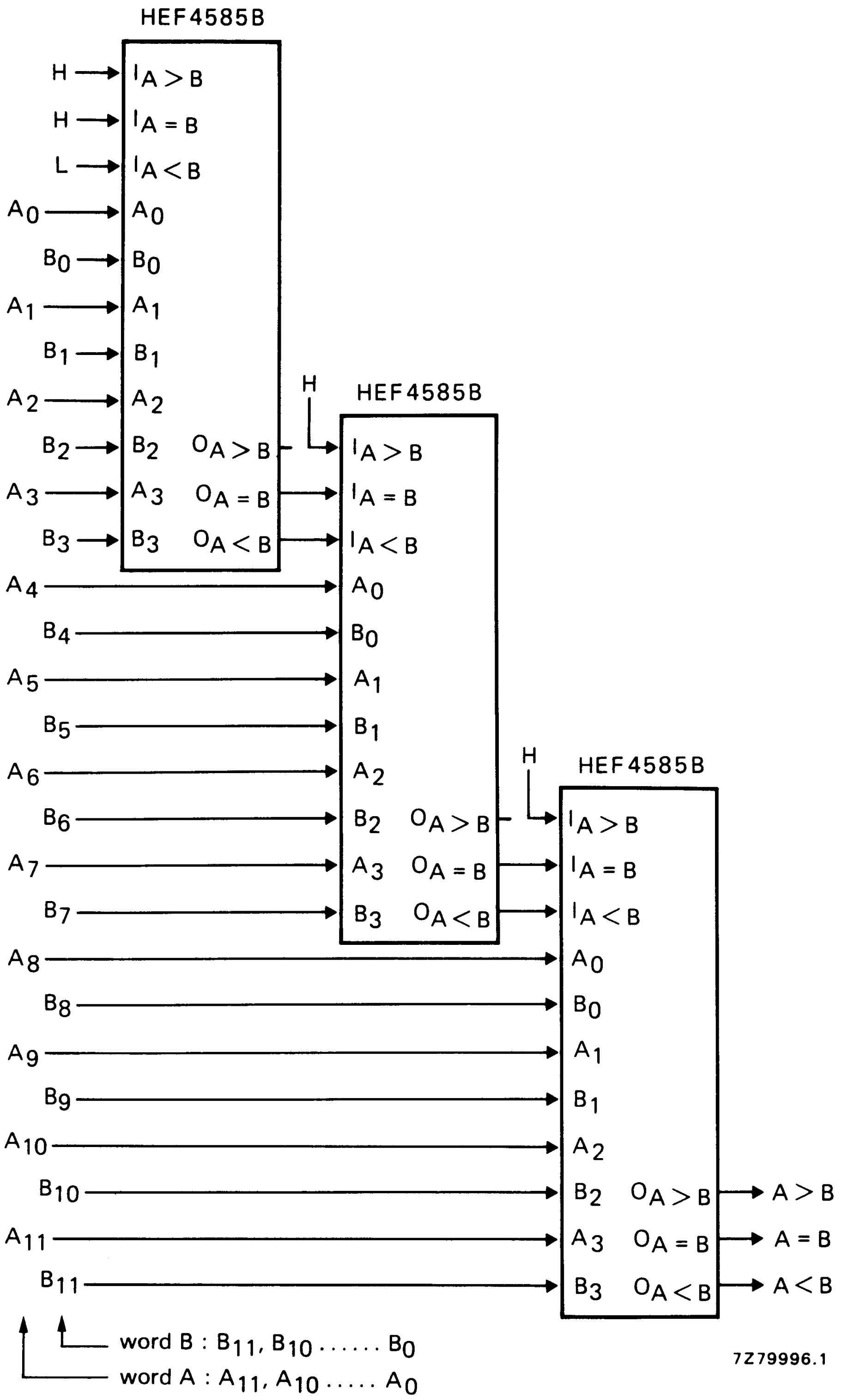

Fig.4 Example of cascading comparators.